

ZXTN2010G

60V NPN MEDIUM POWER LOW SATURATION TRANSISTOR SOT223

Features

- BV_{CEO} > 60V
- I_C = 6A Continuous Collector Current
- I_{CM} = 20A Peak Pulse Current
- Low Saturation Voltage V_{CE(SAT)} < 60mV Max @ 1A
- $R_{SAT} = 35m\Omega$ @ $I_c = 6A$ for Low Equivalent On-Resistance
- h_{FE} Specified up to 10A for High Gain Hold Up
- Lead-Free Finish; RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability

Mechanical Data

- Case: SOT223
- Case Material: Molded Plastic. "Green" Molding Compound;
 UL Flammability Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Plated Leads; Solderable per MIL-STD-202, Method 208 ³
- Weight: 0.112 grams (Approximate)

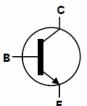
Applications

- Emergency Lighting Circuits
- Motor Driving (Including DC Fans)
- Solenoid, Relay and Actuator Drivers
- DC Modules
- Backlight Inverters

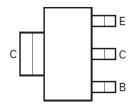
SOT223



Top View



Device Schematic



Pin-Out Top View

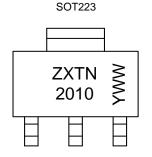
Ordering Information (Note 4)

Part Number	Marking	Reel size (inches)	Tape width (mm)	Quantity per reel
ZXTN2010GTA	ZXTN2010	7	12	1,000

Notes: 1. EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant. All applicable RoHS exemptions applied.

- 2. See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- ${\it 4. For packaging details, go to our website at http://www.diodes.com/products/packages.html.}\\$

Marking Information



ZXTN 2010 = Product Type Marking Code YWW = Date Code Marking Y or \overline{Y} = Last Digit of Year (ex: 5= 2015) WW or $\overline{W}W$ = Week Code (01~53)



Absolute Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V_{CBO}	150	V
Collector-Emitter Voltage	V _{CEO}	60	V
Emitter-Base Voltage	V_{EBO}	7	V
Continuous Collector Current	Ic	6	А
Peak Pulse Current	I _{CM}	20	A

Thermal Characteristics (@TA = +25°C, unless otherwise specified.)

Characteristic		Symbol	Value	Unit	
Power Dissipation	(Note 5)	D.	3.0 24	W mW/°C	
Linear Derating Factor	(Note 6)	P _D	1.6 12.8		
Thermal Decistores, Junction to Ambient	(Note 5)	$R_{ heta JA}$	42		
Thermal Resistance, Junction to Ambient	(Note 6)	$R_{ heta JA}$	78	°C/W	
Thermal Resistance, Junction to Lead	$R_{ heta JL}$	8.8			
Operating and Storage Temperature Range		T _J , T _{STG}	-55 to +150	°C	

ESD Ratings (Note 8)

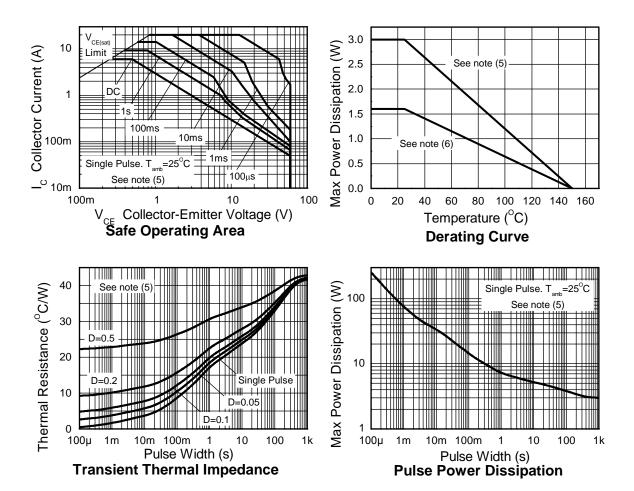
Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge - Human Body Model	ESD HBM	4,000	V	3A
Electrostatic Discharge - Machine Model	ESD MM	400	V	С

Notes:

- 5. For a device mounted with the collector lead on 52mm x 52mm 2oz copper that is on a single-sided 1.6mm FR4 PCB; device is measured under still air 5. For a device mounted with the collector lead on 52mm x 52mm 2oz copper that is conditions whilst operating in steady-state.
 6. Same as Note 5, except the device is mounted on 25mm x 25mm 1oz copper.
 7. Thermal resistance from junction to solder-point (at the end of the collector lead).
 8. Refer to JEDEC specification JESD22-A114 and JESD22-A115.



Thermal Characteristics and Derating Information





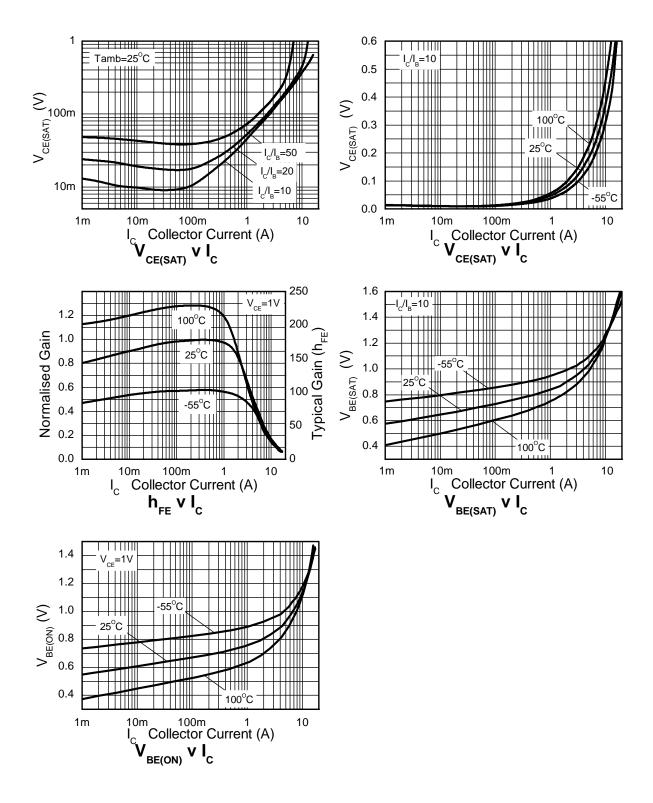
Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
Collector-Base Breakdown Voltage		150	190	_	V	I _C = 100μA
Collector-Emitter Breakdown Voltage		150	190	_	V	$I_C = 1\mu A$, RB $\leq 1k\Omega$
Collector-Emitter Breakdown Voltage (Note 9)		60	80	_	V	I _C = 10mA
Emitter-Base Breakdown Voltage	BV _{EBO}	7	8.1	_	V	I _E = 100μA
Collector Cut-Off Current	lana	_	_	50	nA	V _{CB} = 120V
Collector Cut-Off Current	I _{CBO}	_	-	0.5	μΑ	$V_{CB} = 120V, T_A = +100^{\circ}C$
Collector Cut-Off Current	ICER	_	_	100	nA	V _{CB} = 120V
Concetor Out On Current	R≤1kΩ	_	_	0.5	μΑ	$V_{CB} = 120V, T_A = +100^{\circ}C$
Emitter Cut-Off Current	I _{EBO}		-	10	nA	$V_{EB} = 6V$
		_	20	30		$I_C = 0.1A, I_B = 5mA$
	VCE(sat)	_	45	60		$I_C = 1A$, $I_B = 100mA$
Collector-Emitter Saturation Voltage (Note 9)		_	50	70	mV	$I_C = 1A$, $I_B = 50mA$
		_	100	135		$I_C = 2A$, $I_B = 50mA$
		_	210	260		$I_C = 6A$, $I_B = 300mA$
Base-Emitter Saturation Voltage (Note 9)		_	1	1.1	V	$I_C = 6A$, $I_B = 300mA$
Base-Emitter Turn-on Voltage (Note 9)		_	0.94	1.05	V	$I_C = 6A$, $V_{CE} = 1V$
	V _{BE(on)}	100	200	_		I _C = 10mA, V _{CE} = 1V
DC Current Gain (Note 9)		100	200	300		$I_C = 2A, V_{CE} = 1V$
DC Current Gain (Note 9)		55	105	_		$I_C = 5A$, $V_{CE} = 1V$
		20	40	_		$I_C = 10A, V_{CE} = 1V$
Transition Frequency	f _T	_	130	_	MHz	$V_{CE} = 10V, I_{C} = 100mA,$
, ,						f = 50MHz
Output Capacitance (Note 9)		_	31	_	pF	V _{CB} = 10V, f = 1MHz
Switching Times	t _{ON}	_	42	_	ns	$V_{CC} = 10V, I_C = 1A,$
Switching Times	toff	_	760	_	115	$I_{B1} = -I_{B2} = 100 \text{mA}$

Note: 9. Measured under pulsed conditions. Pulse width \leq 300 μ s. Duty cycle \leq 2%.



Typical Electrical Characteristics (@TA = +25°C, unless otherwise specified.)

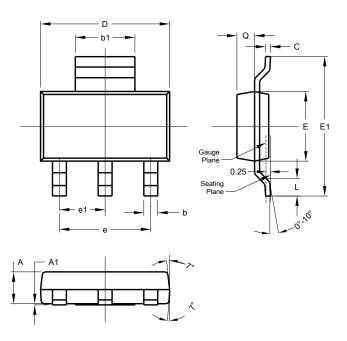




Package Outline Dimensions

Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for the latest version.

SOT223

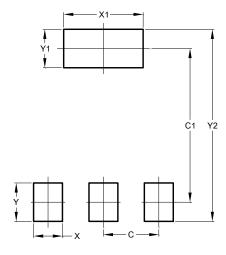


SOT223					
Dim	Min	Max	Тур		
Α	1.55	1.65	1.60		
A1	0.010	0.15	0.05		
b	0.60	0.80	0.70		
b1	2.90	3.10	3.00		
С	0.20	0.30	0.25		
D	6.45	6.55	6.50		
Е	3.45	3.55	3.50		
E1	6.90	7.10	7.00		
е	-	-	4.60		
e1	-	-	2.30		
L	0.85	1.05	0.95		
Q	0.84	0.94	0.89		
All Dimensions in mm					

Suggested Pad Layout

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.

SOT223



Dimensions	Value (in mm)		
C	2.30		
C1	6.40		
Х	1.20		
X1	3.30		
Y	1.60		
Y1	1.60		
Y2	8.00		



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